## NSN 5961-01-023-8512

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Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown
voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
800.00 milliamperes source cutoff current
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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